

Analysis and application of two-current-source circuit as a signal conditioner for resistive sensors

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The article presents the analysis of metrological properties of a two-current-source supplied circuit. It includes such data as precise and simplified equations for two circuit output voltages in the function of relative resistance increments of sensors. Moreover, graphs showing nonlinearity coefficients of both output voltages for two resistance increments varying widely are presented. Graphs of transfer resistances, depending on relative increments of sensors resistance were also created. The article also contains a description of bridge-based circuit realization with the use of a computer and a data acquisition (DAQ) card. Laboratory measurement of the difference and sum of relative resistance increments of two resistance decade boxes were carried out indirectly with the use of the created measurement system. Measurement errors were calculated and included in the article, as well.

Key words: error analysis, measurement techniques, sensor systems

1 Introduction

Measurement methods exploit classic bridge circuits as transducers of resistance changes into voltage and use them for preliminary signal conditioning [1, 2]. The accuracy of the bridge circuit depends on resistance precision placed in its branch and has significant influence on precision of the whole measurement chain [3]. Theoretic works concerning new possibilities of parallel measurement of two or more quantities (or their components) have appeared in literature since 2000. The research is done with the use of classic or unconventional bridge-based measurement systems [4–6].

In [4] using those systems to build new measurement devices was also taken into consideration. The change of the way of supplying the bridge (using two direct current sources) was the novelty of this solution. Following works presented the idea of a two-current-supply automatically charge-balanced bridge [5]. According to the authors' knowledge, however, this research has not been continued.

Other solutions presented in literature are based on classic Wheatstone's bridge architecture. Unfortunately, they have separate sensors for each measured quantity, separate channels of classical unbalanced bridges and one common (current or voltage) power source. Output voltages are then measured sequentially, by switching from one bridge circuit to another. Continuous switching arms of a bridge and measuring the output voltage in each cycle is another way of measuring many physical quantities simultaneously. Anderson's loop, worked out for NASA purposes in the 1990s, is an alternative solution for classical unbalanced bridge [7, 8]. Resistance sensors in such a system are connected serial to a power supply and a

reference resistor. The measurement of resistance increments is done through subtraction voltages with the use of functional blocks equipped with measurement amplifiers.

Typically, resistive elements are combined into full Wheatstone bridge, for example in AMR sensors [9].

Because of the shortage of works concerning systems used for simultaneous measurement of many physical quantities [10] or impedance components [11], the authors of this paper decided to address the problem of constructing improved two-current-supply circuits with analogue voltage outputs. The research resulted in designing and building original prototypes of unbalanced bridges supplied by two identical or switchable DC current sources. It was assumed that, in specific circumstances, those circuits can be used as an alternative for commonly known and applied solutions for simultaneous measurement of two physical quantities. It is worth noting that the results of the research, which are presented in this article, have been patented [12].

2 The analysis of a two-current supplied circuit

A two-current-source bridge circuit described in [4] is only a theoretical solution. The circuit is supplied by two current sources galvanically isolated, and it does not have a permanent connection with the circuit ground. In order to test its metrological qualities, an attempt to physically realize the idea was taken. It was done through modifying the way of supply by introducing one, switchable current source [13].

This article suggests a different measurement system (Fig. 1). It does not have switchable current sources or

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any switching keys. Two sources supply the system permanently. Four resistance sensors R_1, R_2, R_3, R_4 are connected into a four-armed bridge. Two current sources, J_1, J_2 are joined up to the opposite nodes of the circuit. Two reference resistors R_{r1}, R_{r2} (therefore: $2J+2R$) are connected with the other nodes. It was assumed that current efficiency of the sources were identical and unchangeable in time ($J_1 = J_2 = \text{const}$). This means that DC sources of high stability should be applied in this kind of systems. The currents of sources are channeled into A and B nodes.

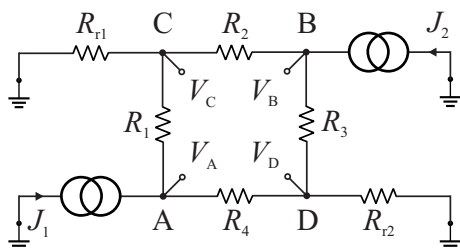


Fig. 1. Two - current - supply circuit ($2J + 2R$)

The circuit described above measures the potential values for A, B, C and D nodes, or voltage between D–C and A–B nodes. Below, a matrix equation describing dependences between electric values in this measurement system is presented. It shows that the measured potentials depend on resistance of particular arms of the system and current efficiency of both supplies

$$\begin{bmatrix} \frac{R_1+R_4}{R_1R_4} & 0 & -\frac{1}{R_1} & -\frac{1}{R_4} \\ 0 & \frac{R_2+R_3}{R_2R_3} & -\frac{1}{R_2} & -\frac{1}{R_3} \\ -\frac{1}{R_1} & -\frac{1}{R_2} & \frac{R_1R_2+(R_1+R_2)R_{r1}}{R_1R_2R_{r1}} & 0 \\ -\frac{1}{R_4} & -\frac{1}{R_3} & 0 & \frac{R_3R_4+(R_3+R_4)R_{r2}}{R_3R_4R_{r2}} \end{bmatrix} \times [V_A \ V_B \ V_C \ V_D]^T = [J_1 \ J_2 \ 0 \ 0]^T \quad (1)$$

where V_A, V_B, V_C, V_D are the potentials in A, B, C and D nodes.

Resistances in arms change under influence of measured quantities (eg deflection or temperature). It is presented in the following equation

$$R_i = R_{i0}(1 + \varepsilon_i), \quad \text{for } i = 1, 2, 3, 4, \quad (2)$$

where R_{i0} is the initial (nominal) resistance, ΔR_i is the absolute resistance increment, $\varepsilon_i = \Delta R_i/R_{i0}$ is the relative resistance increment of the i -th sensor.

As it was mentioned previously, equal values of current in both sources were assumed and also the values of reference resistors are equal the nominal resistance of the sensors

$$J = J_1 = J_2, \quad (3a)$$

$$R_{10} = R_{20} = R_{30} = R_{40} = R_0, \quad (3b)$$

$$R_{r1} = R_{r2} = R_r = R_0. \quad (3c)$$

Solving equation (1) and substituting (2), (3a), (3b) and (3c) made the following formulas:

$$V_A = \frac{3JR_0(6 + \varepsilon_1 + \varepsilon_4)}{12 + 4(\varepsilon_1 + \varepsilon_2 + \varepsilon_3 + \varepsilon_4) + (\varepsilon_1 + \varepsilon_4)(\varepsilon_2 + \varepsilon_3)}, \quad (4)$$

$$V_B = \frac{3JR_0(6 + \varepsilon_2 + \varepsilon_3)}{12 + 4(\varepsilon_1 + \varepsilon_2 + \varepsilon_3 + \varepsilon_4) + (\varepsilon_1 + \varepsilon_4)(\varepsilon_2 + \varepsilon_3)}, \quad (5)$$

$$V_C = \frac{V_A(1 + \varepsilon_2) + V_B(1 + \varepsilon_1)}{2 + \varepsilon_1 + \varepsilon_2 + (1 + \varepsilon_1)(1 + \varepsilon_2)}, \quad (6)$$

$$V_D = \frac{V_A(1 + \varepsilon_3) + V_B(1 + \varepsilon_4)}{2 + \varepsilon_3 + \varepsilon_4 + (1 + \varepsilon_3)(1 + \varepsilon_4)}. \quad (7)$$

The following step was to calculate output voltages of the circuit with one pair of sensors which means the calculation was done for two increments $\varepsilon_1, \varepsilon_2 \neq 0$, and two other $\varepsilon_3 = \varepsilon_4 = 0$

$$V_D = \frac{V_A(1 + \varepsilon_3) + V_B(1 + \varepsilon_4)}{2 + \varepsilon_3 + \varepsilon_4 + (1 + \varepsilon_3)(1 + \varepsilon_4)} \quad (8)$$

and

$$U_{DC} = V_D - V_C = JR_0 \frac{K(\varepsilon)}{H(\varepsilon)} \quad (9)$$

where:

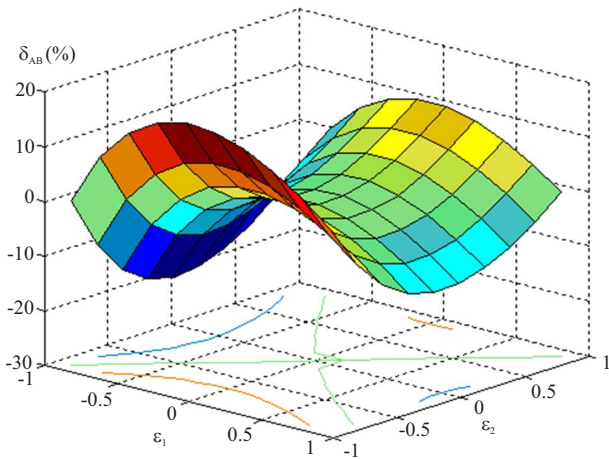
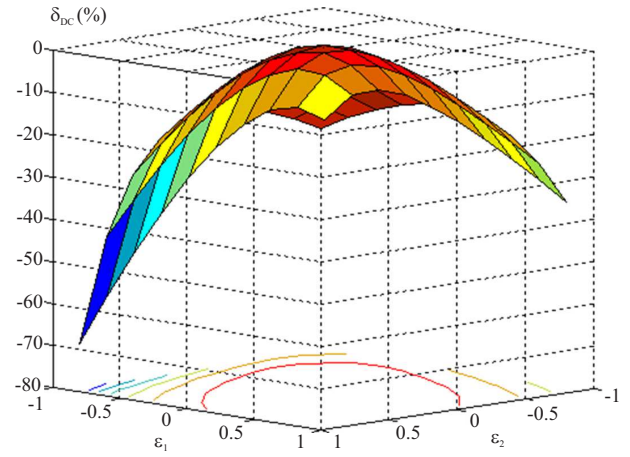
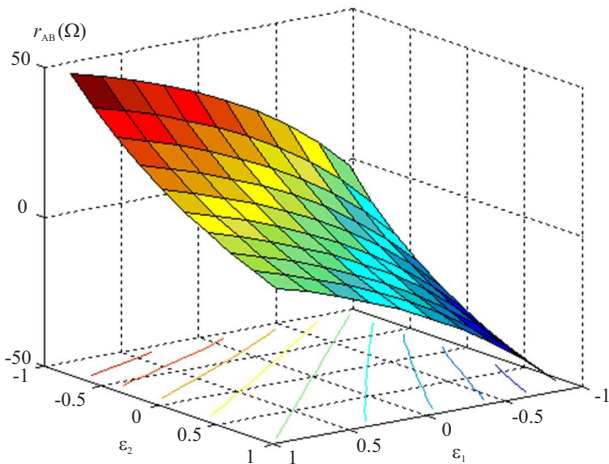
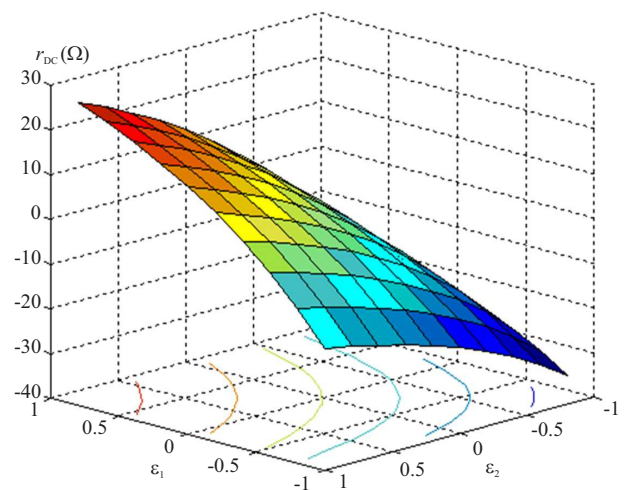
$$\begin{aligned} K(\varepsilon) &= 6(\varepsilon_1 + \varepsilon_2) + 10\varepsilon_1\varepsilon_2 + \varepsilon_1(2\varepsilon_1 + \varepsilon_1\varepsilon_2) \\ &\quad + \varepsilon_2(2\varepsilon_2 + \varepsilon_1\varepsilon_2), \\ H(\varepsilon) &= 36 + 36(\varepsilon_1 + \varepsilon_2) + 15\varepsilon_1\varepsilon_2 + 8(\varepsilon_1 + \varepsilon_2)^2 \\ &\quad + 6(\varepsilon_1 + \varepsilon_2)\varepsilon_1\varepsilon_2 + \varepsilon_1^2\varepsilon_2^2. \end{aligned}$$

The above equations show that for high relative increments $\varepsilon_i \gg 0$ the voltages U_{AB} and U_{DC} are non-linear functions of relative increments ε_i . Whereas, for sensors with low resistance increment $\varepsilon_1, \varepsilon_2$ (when the following conditions occur: $4|\varepsilon_1 + \varepsilon_2| \ll 12$, $36|\varepsilon_1 + \varepsilon_2| \ll 36$ (it results that $|\varepsilon_1 + \varepsilon_2| \ll 1$), $\varepsilon_1^2 \approx 0$, $\varepsilon_2^2 \approx 0$ and $\varepsilon_1\varepsilon_2 \approx 0$), both functions become linear. Making those assumptions, equations (8) and (9) can be simplified so that linear forms of the functions (10) and (11) are obtained

$$U_{ABu} \cong V_A - V_B = \frac{JR_0}{4}(\varepsilon_1 - \varepsilon_2), \quad (10)$$

$$U_{DCu} \cong V_D - V_C = \frac{JR_0}{6}(\varepsilon_1 + \varepsilon_2). \quad (11)$$

The analysis of the equations (10) and (11) proves that the system can work with one pair of resistance sensors. As a result, measuring two increments at the same time, as well as the sum and difference of resistances is possible. This conditions and formulas can be useful in applications with strain gauges, especially when a resistance sensor is differential [14].


Fig. 2. δ_{AB} nonlinearity coefficient in function of ε_1 and ε_2

Fig. 3. δ_{DC} nonlinearity coefficient in function of ε_1 and ε_2

Fig. 4. Transfer resistance r_{AB} of transducer in relation to ε_1 and ε_2 (when $R_r = R_0 = 100 \Omega$)

Fig. 5. Transfer resistance r_{DC} of transducer in relation to ε_1 and ε_2 (when $R_r = R_0 = 100 \Omega$)

Differences between linearized equations (10), (11) and the real ones (8), (9) are described with the use of relative non-linearity coefficients of δ_{AB} and δ_{DC} . These are absolute non-linearity errors [15] related to full measurement ranges of both output voltages

$$\delta_{AB} = \frac{U_{ABu} - U_{AB}}{U_{AB \max} - U_{AB \min}} \cdot 100\%, \quad (12)$$

$$\delta_{DC} = \frac{U_{DCu} - U_{DC}}{U_{DC \max} - U_{DC \min}} \cdot 100\%, \quad (13)$$

where $U_{AB \max} - U_{AB \min} = \Delta_{AB}$, $U_{DC \max} - U_{DC \min} = \Delta_{DC}$ are full ranges of output voltages of the system calculated for minimum (-0.9) and maximum (0.9) value of variable ε_2 where ε_1 is given

$$\Delta_{AB} = U_{AB}(\varepsilon_1, \varepsilon_2 = 0.9) - U_{AB}(\varepsilon_1, \varepsilon_2 = -0.9), \quad (14)$$

$$\Delta_{DC} = U_{DC}(\varepsilon_1, \varepsilon_2 = 0.9) - U_{DC}(\varepsilon_1, \varepsilon_2 = -0.9). \quad (15)$$

The graphs of relative non-linearity coefficients (12), (13) are presented in Figs. 2–5 (for $J = 100 \text{ mA}$ and $R_0 = 100 \Omega$).

Comparing Fig. 2 and Fig. 3 proves that for negative values of ε_1 parameter, the range of changes of the δ_{AB} non-linearity coefficient takes higher values (from about -20% to about $+20\%$) than at $\varepsilon_1 > 0$ (from about -10% to about $+20\%$). It can be observed that for $\varepsilon_1 < 0$ $|\delta_{DC}|$ it takes a slightly higher value (about 70%) than for $\varepsilon_1 > 0$ (about 35%).

Relative increments of resistance in strain gauge sensors are significantly lower than the limiting values ± 0.9 assumed above. For this reason, some additional computations for $|\varepsilon_1| < 0.1$ and $|\varepsilon_2| < 0.1$ were carried out. Modules of non-linearity coefficients $|\delta_{AB}|$ and $|\delta_{DC}|$ within this range are not higher than 0.2% and 0.5% , respectively.

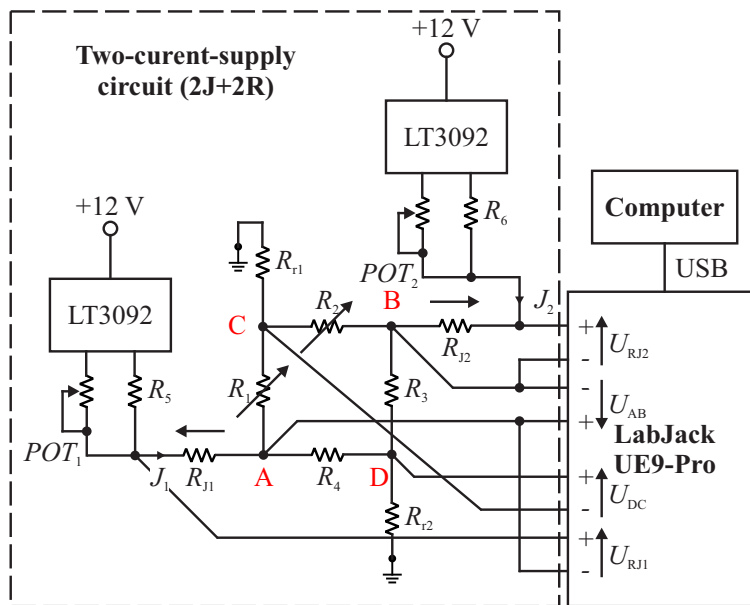


Fig. 6. Measurement system consisting of a two - current - supply circuit ($2j + 2R$), a LabJack measurement module (UE9-Pro) and a PC

Moreover, r_{AB} and r_{DC} transfer resistances were defined as circuit output voltage to supply current J

$$r_{AB} = \frac{U_{AB}}{J}, \quad (16)$$

$$r_{DC} = \frac{U_{DC}}{J} \quad (17)$$

where (8) and (9) were applied. Figures 4 and 5 present r_{AB} and r_{DC} graphs in the function of $\varepsilon_1, \varepsilon_2$ resistance relative increments.

Comparing Figs. 4 and 5 shows that r_{AB} decreases and r_{DC} grows in a function of increasing ε_2 value (assuming that ε_1 value is constant). Moreover, the range of r_{AB} function changes is larger than for r_{DC} function.

3 Two-current-supply circuit realization

A two-current-supply circuit was designed and built. LT3092 systems were used as current sources (Fig. 6). They have great stability and can be regulated within 0.5–200 mA range, and additionally – which is an advantage – do not require applying external capacitors. Their latency time is short (about 20 μ s). The accuracy of the sources currents is 1% and the temperature drift –0.3% within the range of 0–100 °C (at the working current of 1 mA). The sources currents depend on the values adjusted on potentiometers (POT1 and POT2) and on resistance values (R_5 and R_6). The value of the sources current, which was precisely set, equalled $J = 100$ mA and was controlled during experiments through measuring voltage drop (U_{RJ1} and U_{RJ2}) on resistors (R_{J1} and R_{J2}). Reference resistors of the $R_{r1} = R_{r2} = 100 \Omega$ value are joined with C and D points and their free endings –

to the ground of the system. High precision and stability of resistance values in the function of temperature should be their features.

In order to conduct the research, a measurement system consisting of two-current-supply circuit ($2J+2R$), a UE9-Pro LabJack data acquisition module and a PC were used. The LabJack module was equipped with unipolar inputs of the range of 0–5 V. This causes voltage resolution of measurement equal 4.8 μ V at the Analog to Digital Converter set resolution of 20 bits (resolution may change from 16 to 24 bits).

Two resistance decades (MDR-93/2-4a) play the role of variable resistors R_1 and R_2 in the circuit. They were used to set chosen values of resistance increase of sensors. A computer program created in LabVIEW environment was used to acquire, visualize, and store data in a file [16].

4 Laboratory research

The research was aimed at indirect calculating the values of $\varepsilon_R = \varepsilon_1 - \varepsilon_2$ and $\varepsilon_S = \varepsilon_1 + \varepsilon_2$ of the increments of R_1 and R_2 decade resistors relative resistance. For this reason, different combinations of ε_1 and ε_2 relative increments were placed on decades, assuming that $|\varepsilon_1 + \varepsilon_2| \ll 1$ (condition in accordance with assumptions of asymptotic formulas validity (10), (11)).

The change of decade resistance R_1 with a step of $\Delta R_1 = +2.00 \Omega$ (which is a value according to $R_0 = 100 \Omega$ that equals $\varepsilon_1 = +0.02$) and R_2 with a step of $\Delta R_2 = -1.00 \Omega$ (which is $\varepsilon_2 = -0.01$) resistance can be given as examples of this case. Then, the difference of relative increments equals $\varepsilon_R = \varepsilon_1 - \varepsilon_2 = 0.03$ and the sum – $\varepsilon_S = \varepsilon_1 + \varepsilon_2 = 0.01$. After each decade resistance being set in this way, measurement of voltage in both diagonals of the bridge (U_{AB} and U_{DC}) was conducted.

Average values (\overline{U}_{AB} and \overline{U}_{DC}) and standard deviations $\sigma_{U_{AB}}$, $\sigma_{U_{DC}}$ (Tab. 1) were calculated on the basis of simultaneously recorded instantaneous voltage (U_{AB} and U_{DC}) in series of 1000 samples. It can be observed in Tab. 1 that the $\sigma_{U_{DC}} \gg \sigma_{U_{AB}}$ inequality occurs for a given variant of decades setting. This proves that voltage functions of U_{DC} are greater than those of U_{AB} .

Table 1. Measurement results of average voltage values at the diagonals of the circuit for different combinations of relative resistance increments (1000 samples acquired every 0.1 s).

No.	Set values		Measured values			
	ε_1	ε_2	\overline{U}_{AB} (mV)	$\sigma_{U_{AB}}$ (mV)	\overline{U}_{DC} (mV)	$\sigma_{U_{DC}}$ (mV)
1	0.00	0.00	0.0019	0.0005	1.1138	0.6392
2	0.00	-0.01	-18.289	0.0028	27.163	0.4166
3	0.00	-0.02	-34.899	0.0340	52.461	0.5280
4	0.01	-0.01	-1.772	0.0118	51.611	0.4873
5	0.01	-0.02	-18.288	0.0036	77.415	0.3463
6	0.02	-0.01	15.300	0.0021	75.979	0.3977
7	0.02	-0.02	-1.797	0.0031	94.462	0.3875

Then, equations (10) and (11) were transformed to the following forms

$$\overline{\varepsilon}_{RW} = 4 \frac{\overline{U}_{AB}}{J R_0}, \quad (18)$$

$$\overline{\varepsilon}_{SW} = 6 \frac{\overline{U}_{DC}}{J R_0}. \quad (19)$$

Differences and sums of two relative resistance increments for average voltage values \overline{U}_{AB} , \overline{U}_{DC} were calculated according to (18) and (19). Further, relative differences e_R and e_S between the calculated (average) $\overline{\varepsilon}_{RW}$ and $\overline{\varepsilon}_{SW}$ values, and values ε_R and ε_S set on the decades were defined.

$$|e_R| = \frac{|\varepsilon_R| - |\overline{\varepsilon}_{RW}|}{|\varepsilon_R|} \cdot 100\%, \quad (20)$$

$$|e_S| = \frac{|\varepsilon_S| - |\overline{\varepsilon}_{SW}|}{|\varepsilon_S|} \cdot 100\%. \quad (21)$$

Table 2. The values of relative resistance increments set into decades, values calculated by measurement equations, and received relative differences

No.	Set values				Calculated from (18) and (19)		Relative differences (20) and (21)	
	ε_1	ε_2	e_R	e_S	$\overline{\varepsilon}_{RW}$	$\overline{\varepsilon}_{SW}$	$ e_R $ %	$ e_S $ %
1	0.00	0.00	0.00	0.00	0.00045	0.00000	—	—
2	0.00	-0.01	0.01	-0.01	0.01086	-0.01095	8.65	9.50
3	0.00	-0.02	0.02	-0.02	0.02098	-0.02094	4.92	4.70
4	0.01	-0.01	0.02	0.00	0.02064	-0.00106	3.22	—
5	0.01	-0.02	0.03	-0.01	0.03097	-0.01097	3.22	9.70
6	0.02	-0.01	0.03	0.01	0.03039	0.00918	1.31	8.20
7	0.02	-0.02	0.04	0.00	0.03778	-0.00108	5.54	—

Table 2 contains differences and sums of ε_1 and ε_2 relative increments. Moreover, values of e_R and e_S relative differences are given there. As it can be observed, the differences are not greater than 9.7% within the tested area $\varepsilon_1 - \varepsilon_2 \ll 0.04$.

5 Conclusions

The presented analysis of output voltage functions shows that, for $|\varepsilon_1 + \varepsilon_2| \ll 1$ condition, simplified equations (10) and (11) can be applied to calculate U_{AB} and U_{DC} voltages. For changes of both parameters within $|\varepsilon_1| \leq 0.9$ and $|\varepsilon_2| \leq 0.9$, the nonlinearity coefficient module $|\delta_{AB}|$ increments up to 20% in extreme cases (Fig. 2), and $|\delta_{DC}|$ coefficient to 70% (Fig. 3). If the range of both parameters is shrunk to $|\varepsilon_1| < 0.1$ and $|\varepsilon_2| < 0.1$, the modules of coefficients $|\delta_{AB}|$ and $|\delta_{DC}|$ are not greater than 0.2% and 0.5% respectively. In the case of strain gauges, the ε_1 and ε_2 values change within the range of -0.02 to 0.02. The values of both nonlinearity values are then placed within the range of $\pm 0.2\%$. For this reason, equations (10) and (11) are precise enough.

The constructed bridge circuit (Figs. 6, 7) enabled, indirectly, laboratory measurement of $\varepsilon_R = \varepsilon_1 - \varepsilon_2$ and $\varepsilon_S = \varepsilon_1 + \varepsilon_2$ of resistance relative increments of R_1 and R_2 decade resistors. The measurements show that relative differences of sums and differences of $\overline{\varepsilon}_{RW}$ and $\overline{\varepsilon}_{SW}$ increments are not greater than 9.7% (Tab. 2). This proves that the constructed circuit (Figs. 6, 7) works (with acceptable error) according to created equations (10) and (11).

Another work will contain comparison of metrological properties of the bridge circuit with other circuits used for simultaneous measurement of two physical quantities.

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